



CMNDM7001

SURFACE MOUNT  
N-CHANNEL  
ENHANCEMENT-MODE  
SILICON MOSFET

FEMTOmini™



SOT-953 CASE

- Device is *Halogen Free* by design

**APPLICATIONS:**

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Powered Portable Equipment

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Drain-Source Voltage	
Gate-Source Voltage	
Continuous Drain Current (Steady State)	
Continuous Drain Current	
Power Dissipation	
Operating and Storage Junction Temperature	

**Central**<sup>TM</sup>  
**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMNDM7001 is an Enhancement-mode N-Channel MOSFET, manufactured by the N-Channel DMOS Process, designed for high speed pulsed amplifier and driver applications. This MOSFET offers Low  $r_{DS(\text{ON})}$  and Low Threshold Voltage.

**MARKING CODE: AC****FEATURES:**

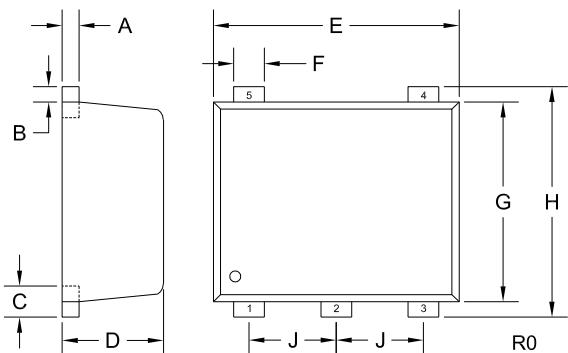
- Low 0.5mm Package Profile
- Low  $r_{DS(\text{ON})}$
- Low Threshold Voltage
- Logic Level Compatible
- Small, FEMTOmini™ 1.0 x 0.8mm, SOT-953 Surface Mount Package

SYMBOL		UNITS
$V_{DS}$	20	V
$V_{GS}$	10	V
$I_D$	100	mA
$I_D$	200	mA
$P_D$	250	mW
$T_J, T_{stg}$	-65 to +150	°C

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_{GSSF}, I_{GSSR}$	$V_{GS}=10\text{V}, V_{DS}=0$			1.0	µA
$I_{DSS}$	$V_{DS}=20\text{V}, V_{GS}=0$			1.0	µA
$BV_{DSS}$	$V_{GS}=0, I_D=100\mu\text{A}$	20			V
$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.6		0.9	V
$r_{DS(\text{ON})}$	$V_{GS}=4.0\text{V}, I_D=10\text{mA}$			3.0	Ω
$r_{DS(\text{ON})}$	$V_{GS}=2.5\text{V}, I_D=10\text{mA}$			4.0	Ω
$r_{DS(\text{ON})}$	$V_{GS}=1.5\text{V}, I_D=1.0\text{mA}$			15	Ω
$g_{fs}$	$V_{DS}=10\text{V}, I_D=100\text{mA}$	100			µS
$C_{rss}$	$V_{DS}=3.0\text{V}, V_{GS}=0, f=1.0\text{MHz}$		4.0		pF
$C_{iss}$	$V_{DS}=3.0\text{V}, V_{GS}=0, f=1.0\text{MHz}$		9.0		pF
$C_{oss}$	$V_{DS}=3.0\text{V}, V_{GS}=0, f=1.0\text{MHz}$		9.5		pF
$t_{on}$	$V_{DD}=3.0\text{V}, V_{GS}=2.5\text{V}, I_D=10\text{mA}$		50		ns
$t_{off}$	$V_{DD}=3.0\text{V}, V_{GS}=2.5\text{V}, I_D=10\text{mA}$		75		ns

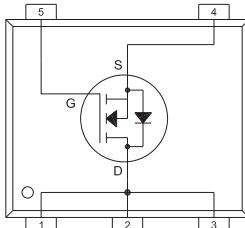
**SOT-953 - MECHANICAL OUTLINE**



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.006	0.050	0.150
B	0.002	0.006	0.050	0.150
C	0.005	0.007	0.125	0.175
D	0.016	0.020	0.400	0.500
E	0.037	0.041	0.950	1.050
F	0.004	0.008	0.100	0.200
G	0.030	0.033	0.750	0.850
H	0.037	0.041	0.950	1.050
J	0.014		0.350	

SOT-953 (REV: R0)

**PIN CONFIGURATION**



**LEAD CODE:**

- 1) DRAIN
- 2) DRAIN
- 3) DRAIN
- 4) SOURCE
- 5) GATE

**MARKING CODE: AC**

R0 (24-September 2009)